





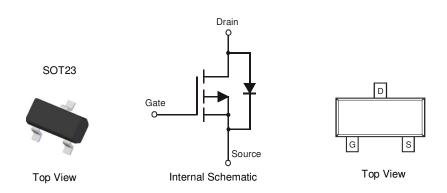
#### P-CHANNEL ENHANCEMENT MODE MOSFET

### **Features**

- Low R<sub>DS(ON)</sub>:
  - $75m\Omega$  @V<sub>GS</sub> = -4.5V
  - 110m $\Omega$  @V<sub>GS</sub> = -2.7V
  - 125m $\Omega$  @V<sub>GS</sub> = -2.5V
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT23
- Case Material Molded Plastic, "Green" Molding Compound.
  UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
  Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)



# Ordering Information (Note 4)

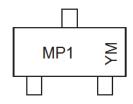
Part Number	Case	Packaging
DMP2130L-7	SOT23	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

# **Marking Information**

Notes:



MP1 = Product Type Marking Code YM or  $\overline{Y}M$  = Date Code Marking Y or  $\overline{Y}$  = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

Year	2007	~	2019	2020	202	1 20	)22	2023	2	2024	2025	2026	2027
Code	U	~	G	Н	1		J	K		L	M	N	0
Month	Jan	Feb	Mar	Apr	May	Jun	Ju	I Au	ıg	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	3	9	0	N	D



# $\hline \textbf{Maximum Ratings} \ (@T_A = +25^{\circ}C, \ unless \ otherwise \ specified.)$

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	-20	V
Gate-Source Voltage		V <sub>GSS</sub>	±12	V
Drain Current (Note 5) Continuous	$T_A = +25$ °C $T_A = +70$ °C	I <sub>D</sub>	-3.0 -2.4	А
Pulsed Drain Current (Note 6)		I <sub>DM</sub>	-15	A
Body-Diode Continuous Current (Note 5)		Is	-2.0	Α

# **Thermal Characteristics**

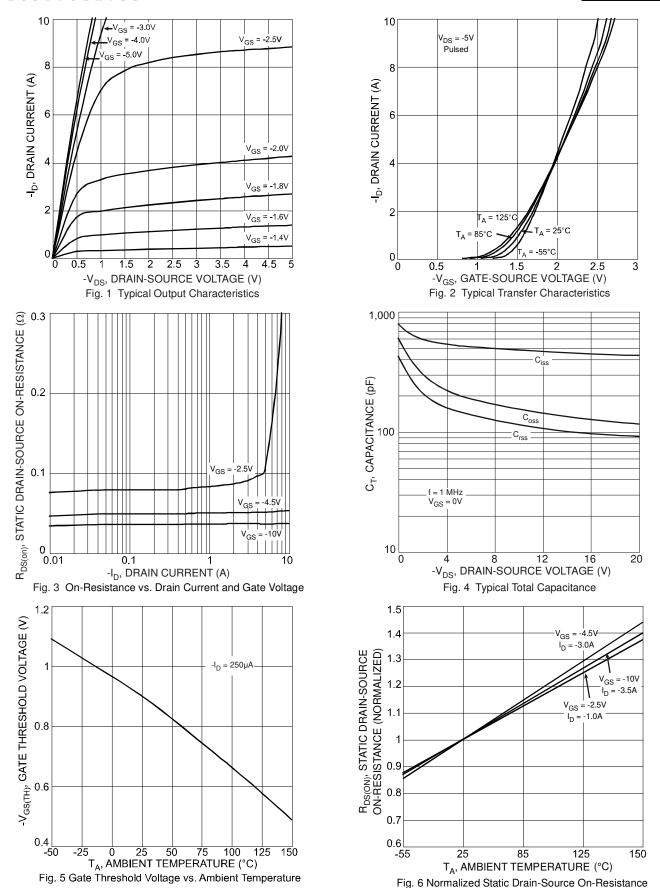
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	$P_{D}$	1.4	W
Thermal Resistance, Junction to Ambient (Note 5); Steady-State	$R_{ hetaJA}$	90	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
STATIC PARAMETERS								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	_	_	V	$I_D = -250 \mu A, V_{GS} = 0 V$		
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	_	_	-1	μΑ	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V		
Gate-Body Leakage Current	I <sub>GSS</sub>	_	_	±100	nA	$V_{DS} = 0V, V_{GS} = \pm 12V$		
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.6	_	-1.25	V	$V_{DS} = V_{GS}, \ I_D = -250 \mu A$		
On State Drain Current (Note 7)	I <sub>D(ON)</sub>	-15	_	_	Α	$V_{GS} = -4.5V, V_{DS} = -5V$		
			51	75		$V_{GS} = -4.5V$ , $I_D = -3.5A$		
Static Drain-Source On-Resistance (Note 7)	R <sub>DS(ON)</sub>	_	87	110	$m\Omega$	$V_{GS} = -2.7V$ , $I_D = -3.0A$		
			99	125		$V_{GS} = -2.5V, I_D = -2.6A$		
Forward Transconductance (Note 7)	<b>g</b> FS	_	7.3	_	S	$V_{DS} = -10V, I_{D} = -3.0A$		
Diode Forward Voltage (Note 7)		_	-0.79	-1.26	V	I <sub>S</sub> = -1.7A, V <sub>GS</sub> = 0V		
Maximum Body-Diode Continuous Current (Note 5)	Is	_	_	1.7	Α	_		
DYNAMIC PARAMETERS (Note 8)								
Total Gate Charge	$Q_g$	_	7.3	_	nC	$V_{GS} = -4.5V$ , $V_{DS} = -10V$ , $I_D = -3.0A$		
Gate-Source Charge	$Q_{gs}$	_	2.0	_	nC	$V_{GS} = -4.5V, V_{DS} = -10V, I_D = -3.0A$		
Gate-Drain Charge	Q <sub>gd</sub>	_	1.9	_	nC	$V_{GS} = -4.5V, V_{DS} = -10V, I_D = -3.0A$		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	12	_	ns			
Turn-On Rise Time		_	20	_	ns	$V_{DS} = -10V, V_{GS} = -4.5V,$		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	38	_	ns	$R_L = 10\Omega, R_G = 6\Omega$		
Turn-Off Fall Time	t <sub>F</sub>	_	41	_	ns			
Input Capacitance	C <sub>iss</sub>	_	443		pF			
Output Capacitance		_	128	_	pF	V <sub>DS</sub> = -16V, V <sub>GS</sub> = 0V f = 1.0MHz		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	101	_	pF	= 1.0IVID2		

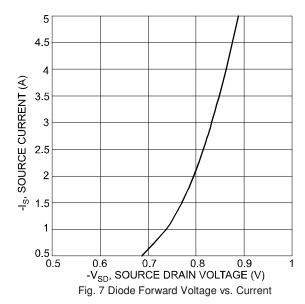
5. Device mounted on 1"x1", FR-4 PC board with 2 oz. copper and test pulse width t  $\leq$ 10s. 6. Repetitive Rating, pulse width limited by junction temperature. 7. Test pulse width t = 300 $\mu$ s. 8. Guaranteed by design. Not subject to production testing. Notes:

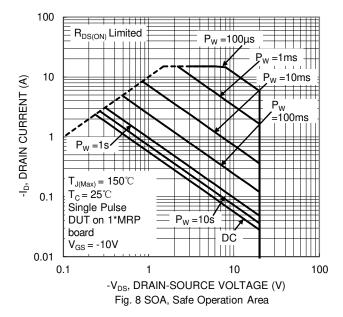


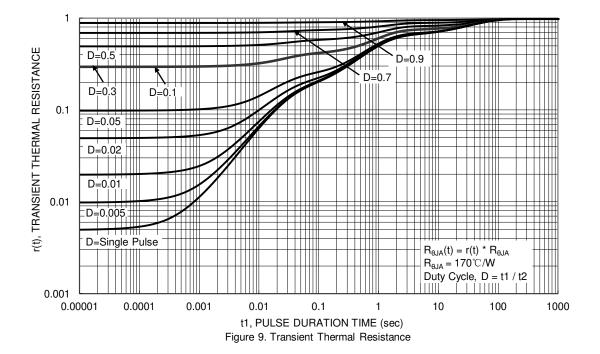


vs. Ambient Temperature









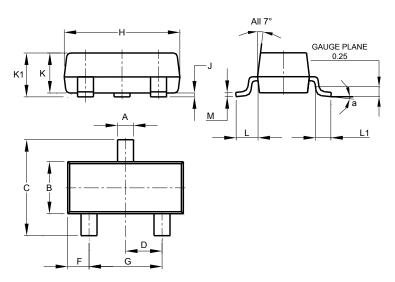
www.diodes.com



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

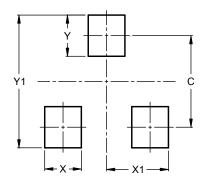


SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
C	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
7	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Υ	0.9
V1	29



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